



100V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D T _C = +25°C	
100V	$5m\Omega @V_{GS} = 10V$	140A	

Description

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high-efficiency power management applications.

Applications

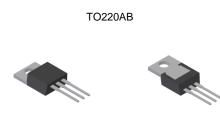
- Motor Control
- Backlighting
- DC-DC Converters
- **Power Management Functions**

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low Input Capacitance
- High BV_{DSS} Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

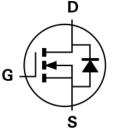
- Case: TO220AB
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)



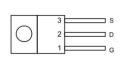




Bottom View



Equivalent Circuit



Top View Pin Out Configuration

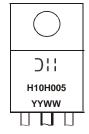
Ordering Information (Note 4)

Part Number	Case	Packaging	
DMTH10H005LCT	TO220AB	50 Pieces/Tube	

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



The Manufacturer's Marking H10H005 = Product Type Marking Code YYWW = Date Code Marking YY or YY = Last Two Digits of Year (ex: 16 = 2016) WW or WW = Week Code (01 to 53)

DMTH10H005LCT Document number: DS38718 Rev. 4 - 2 Downloaded From Oneyac.com



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage	V_{DSS}	100	V	
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ΙD	140 99	А
Maximum Continuous Body Diode Forward Current	T _C = +25°C	I _S	100	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	150	Α	
Avalanche Current, L = 3mH (Note 7)	I _{AS}	19	Α	
Avalanche Energy, L = 3mH (Note 7)	Eas	542	mJ	
Avalanche Current, L = 0.1mH	I _{AS}	25	Α	
Avalanche Energy, L = 0.1mH	E _{AS}	31.2	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T _A = +25°C	P_{D}	2.9	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	51	°C/W
Total Power Dissipation	T _C = +25°C	P _D	187	W
Thermal Resistance, Junction to Case		R _{0JC}	0.8	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

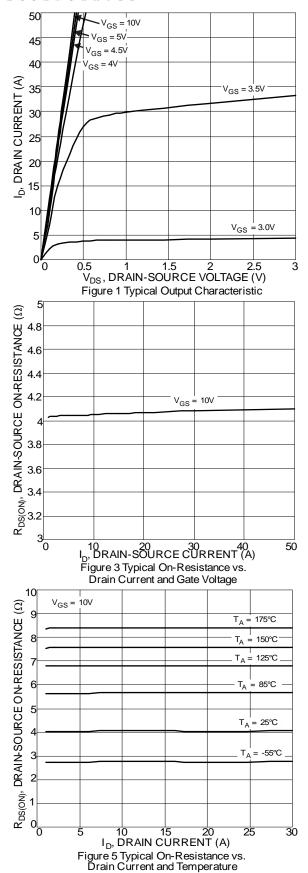
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	_	1	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	1	_	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V _{GS(TH)}	1.4	1.9	3.5	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	1	4	5	mΩ	$V_{GS} = 10V, I_D = 13A$	
Diode Forward Voltage	V_{SD}	_	0.8	1.3	V	$V_{GS} = 0V, I_{S} = 13A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	C _{iss}	_	3688	_		$V_{DS} = 50V$, $V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	1494		pF		
Reverse Transfer Capacitance	C _{rss}	_	48	_			
Gate Resistance	R _G	_	0.75	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Q_{G}	_	114	_		V _{DD} = 50V, I _D = 13A, V _{GS} = 10V	
Gate-Source Charge	Q_GS	_	22.5	_	nC		
Gate-Drain Charge	Q_{GD}	_	17.6	_			
Turn-On Delay Time	t _{D(ON)}	_	25	_		$V_{DD} = 50V, V_{GS} = 10V,$ $I_{D} = 13A, R_{G} = 6\Omega$	
Turn-On Rise Time	t _R	_	26.9		ns		
Turn-Off Delay Time	t _{D(OFF)}	_	83.6	_	115		
Turn-Off Fall Time	t _F		53.1	_			
Reverse Recovery Time	t _{RR}	_	65.5	_	ns	1 12 A di/dt 100 A / v o	
Reverse Recovery Charge	Q_{RR}	_	155.9	_	nC	I _F = 13A, di/dt = 100A/μs	

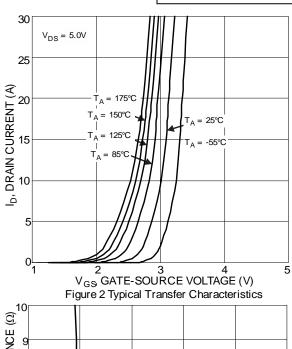
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

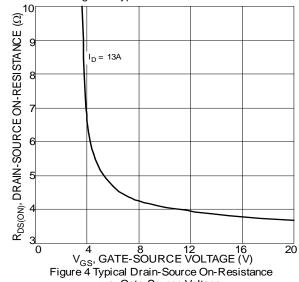
Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

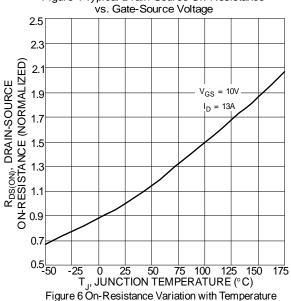






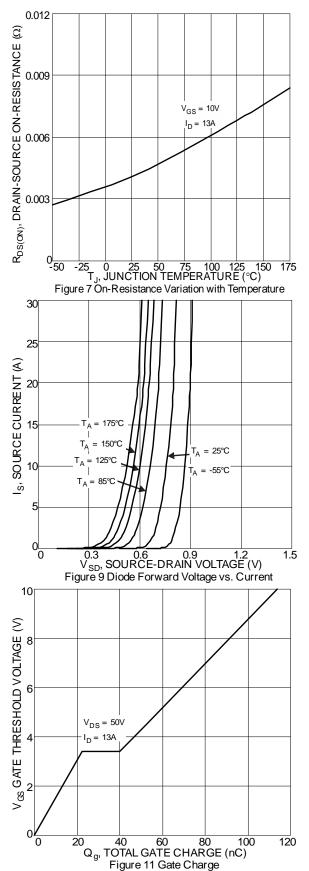


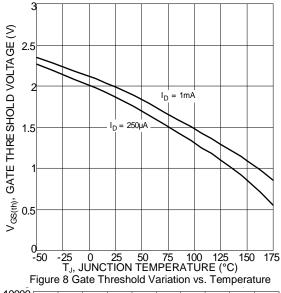


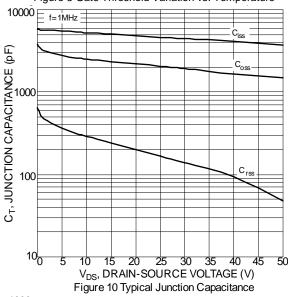


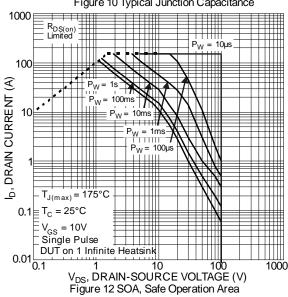














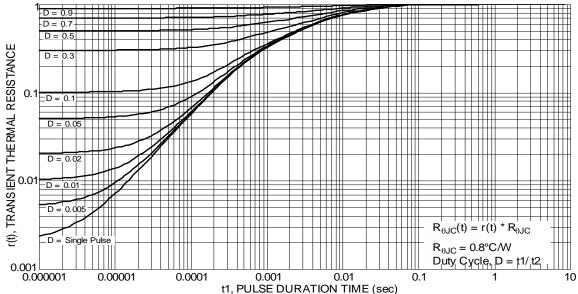


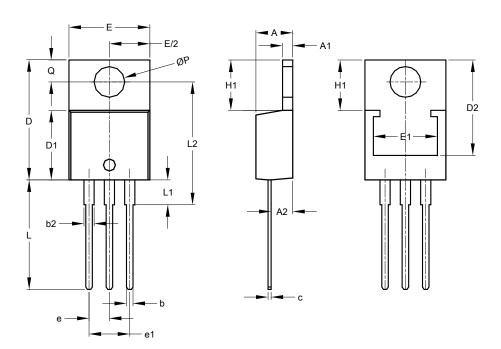
Figure 13 Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO220AB



TO220AB						
Dim	Min	Max	Тур			
Α	3.56	4.82	ı			
A1	0.51	1.39	-			
A2	2.04	2.92	ı			
b	0.39	1.01	0.81			
b2	1.15	1.77	1.24			
С	0.356	0.61	-			
D	14.22	16.51	ı			
D1	8.39	9.01	1			
D2	11.45	12.87	-			
е	-	-	2.54			
e1	-	-	5.08			
Е	9.66	10.66	ı			
E1	6.86	8.89	ı			
H1	5.85	6.85	ı			
L	12.70	14.73	ı			
L1	-	4.42	-			
L2	15.80	17.51	16.00			
Р	3.54	4.08	-			
Q	2.54	3.42	-			
All I	All Dimensions in mm					



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